



LM185-1.2/LM285-1.2/LM385-1.2 Micropower Voltage Reference Diode

General Description

The LM185-1.2/LM285-1.2/LM385-1.2 are micropower 2-terminal band-gap voltage regulator diodes. Operating over a 10 μ A to 20 mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185-1.2 band-gap reference uses only transistors and resistors, low noise and good long term stability result.

Careful design of the LM185-1.2 has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185-1.2 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life.

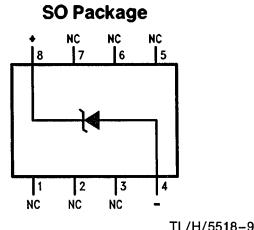
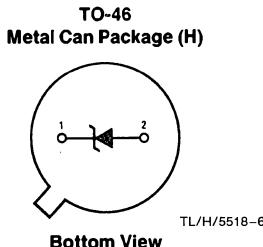
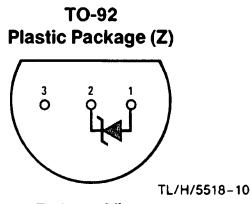
Further, the wide operating current allows it to replace older references with a tighter tolerance part.

The LM185-1.2 is rated for operation over a -55°C to 125°C temperature range while the LM285-1.2 is rated -40°C to 85°C and the LM385-1.2 0°C to 70°C. The LM185-1.2/LM285-1.2 are available in a hermetic TO-46 package and the LM285-1.2/LM385-1.2 are also available in a low-cost TO-92 molded package, as well as S.O.

Features

- ± 4 mV ($\pm 0.3\%$) max. initial tolerance (A grade)
- Operating current of 10 μ A to 20 mA
- 0.6 Ω max dynamic impedance (A grade)
- Low temperature coefficient
- Low voltage reference—1.235V
- 2.5V device and adjustable device also available — LM185-2.5 series and LM185 series, respectively

Connection Diagrams



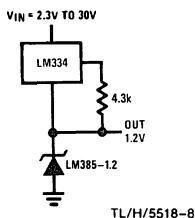
Order Number LM285Z-1.2,
LM285AZ-1.2, LM285AXZ-1.2,
LM285AYZ-1.2,
LM285BXZ-1.2, LM285BYZ-1.2,
LM385Z-1.2, LM385AZ-1.2,
LM385AXZ-1.2, LM385AYZ-1.2,
LM385BXZ-1.2
or LM385BYZ-1.2
See NS Package Number Z03A

Order Number LM185H-1.2,
LM185AH-1.2, LM185AXH-1.2,
LM185AYH-1.2, LM185BXH-1.2,
LM185BYH-1.2, LM285H-1.2,
LM285AH-1.2, LM285AXH-1.2,
LM285AYH-1.2, LM285BXH-1.2
or LM285BYH-1.2
See NS Package Number H02A

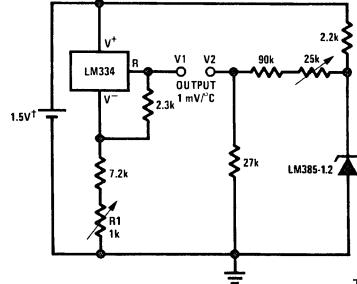
Order Number LM285M-1.2,
LM285AM-1.2, LM285AXM-1.2,
LM285AYM-1.2, LM285BXM-1.2,
LM285BYM-1.2, LM385M-1.2,
LM385AM-1.2, LM385AXM-1.2,
LM385AYM-1.2, LM385BM-1.2,
LM385BXM-1.2 or LM385BYM-1.2
See NS Package Number M08A

Applications

Wide Input Range Reference



Centigrade Thermometer



Calibration

1. Adjust R₁ so that V₁ = temp at 1 mV/ $^{\circ}$ K
2. Adjust V₂ to 273.2 mV
 \dagger I_O for 1.3V to 1.6V battery voltage = 50 μ A to 150 μ A

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

(Note 2)

Reverse Current 30 mA
Forward Current 10 mA

Operating Temperature Range (Note 3)

LM185-1.2 -55°C to +125°C
LM285-1.2 -40°C to +85°C
LM385-1.2 0°C to 70°C

Storage Temperature	-55°C to +150°C
Soldering Information	
TO-92 package: 10 sec.	260°C
TO-46 package: 10 sec.	300°C
SO package: Vapor phase (60 sec.)	215°C
Infrared (15 sec.)	220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Electrical Characteristics (Note 4)

Parameter	Conditions	LM185A-1.2 LM185AX-1.2 LM185AY-1.2 LM285A-1.2 LM285AX-1.2 LM285AY-1.2			LM385A-1.2 LM385AX-1.2 LM385AY-1.2			Units (Limit)
		Typ	Tested Limit (Note 5)	Design Limit (Note 6)	Typ	Tested Limit (Note 5)	Design Limit (Note 6)	
Reverse Breakdown Voltage	$I_R = 100 \mu A$	1.235 1.230	1.231 1.239		1.235 1.235	1.231 1.239		V(Min) V(Max) V(Min) V(Max)
Minimum Operating Current		7	8	10	7	8	10	μA (Max)
Reverse Breakdown Voltage Change with Current	$I_{MIN} \leq I_R \leq 1 \text{ mA}$		1	1.5		1	1.5	mV (Max)
	$1 \text{ mA} \leq I_R \leq 20 \text{ mA}$		10	20		10	20	mV (Max)
Reverse Dynamic Impedance	$I_R = 100 \mu A, f = 20 \text{ Hz}$	0.2		0.6 1.5	0.2		0.6 1.5	Ω (Max)
Wideband Noise (rms)	$I_R = 100 \mu A,$ $10 \text{ Hz} \leq f \leq 10 \text{ kHz}$	60			60			μV
Long Term Stability	$I_R = 100 \mu A, T = 1000 \text{ Hr},$ $T_A = 25^\circ C \pm 0.1^\circ C$	20			20			ppm
Average Temperature Coefficient (Note 7)	$I_{MIN} \leq I_R \leq 20 \text{ mA}$ X Suffix Y Suffix All Others		30 50			30 50		ppm/ $^\circ C$ (Max)
			150				150	

Electrical Characteristics (Continued) (Note 4)

Parameter	Conditions	Typ	LM185-1.2 LM185BX-1.2 LM185BY-1.2 LM285-1.2 LM285BX-1.2 LM285BY-1.2		LM385B-1.2 LM385BX-1.2 LM385BY-1.2		LM385-1.2		Units (Limit)
			Tested Limit (Note 5)	Design Limit (Note 6)	Tested Limit (Note 5)	Design Limit (Note 6)	Tested Limit (Note 5)	Design Limit (Note 6)	
Reverse Breakdown Voltage	$T_A = 25^\circ C$, $10 \mu A \leq I_R \leq 20 mA$	1.235	1.223 1.247		1.223 1.247		1.205 1.260		V(Min) V(Max)
Minimum Operating Current		8	10	20	15	20	15	20	μA (Max)
Reverse Breakdown Voltage Change with Current	$10 \mu A \leq I_R \leq 1 mA$		1	1.5	1	1.5	1	1.5	mV (Max)
	$1 mA \leq I_R \leq 20 mA$		10	20	20	25	20	25	mV (Max)
Reverse Dynamic Impedance	$I_R = 100 \mu A, f = 20 Hz$	1							Ω
Wideband Noise (rms)	$I_R = 100 \mu A$, $10 Hz \leq f \leq 10 kHz$	60							μV
Long Term Stability	$I_R = 100 \mu A, T = 1000 Hr$, $T_A = 25^\circ C \pm 0.1^\circ C$	20							ppm
Average Temperature Coefficient (Note 7)	$I_R = 100 \mu A$ X Suffix Y Suffix All Others		30 50	150	30 50	150		150	ppm/ $^\circ C$ ppm/ $^\circ C$ ppm/ $^\circ C$ (Max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H-1.2 for military specifications.

Note 3: For elevated temperature operation, T_j max is:

LM185 $150^\circ C$

LM285 $125^\circ C$

LM385 $100^\circ C$

Thermal Resistance	TO-92	TO-46	SO-8
θ_{JA} (junction to ambient)	$180^\circ C/W$ (0.4" leads) $170^\circ C/W$ (0.125" leads)	$440^\circ C/W$	$165^\circ C/W$
θ_{JC} (junction to case)	N/A	$80^\circ C/W$	N/A

Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at $T_A = T_j = 25^\circ C$.

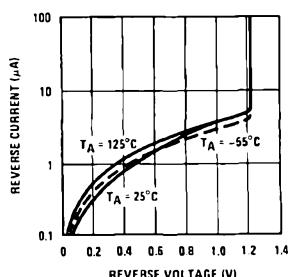
Note 5: Guaranteed and 100% production tested.

Note 6: Guaranteed, but not 100% production tested. These limits are not used to calculate average outgoing quality levels.

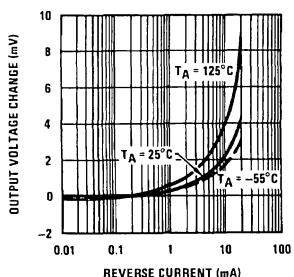
Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN} , divided by $T_{MAX} - T_{MIN}$. The measured temperatures are $-55^\circ C$, $-40^\circ C$, $0^\circ C$, $25^\circ C$, $70^\circ C$, $85^\circ C$, $125^\circ C$.

Typical Performance Characteristics

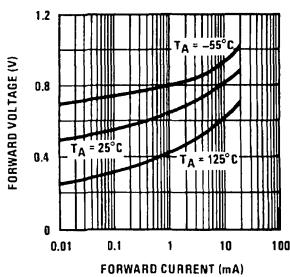
Reverse Characteristics



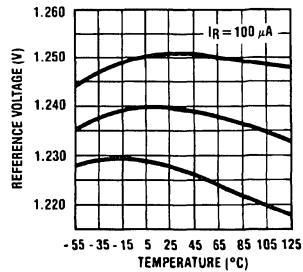
Reverse Characteristics



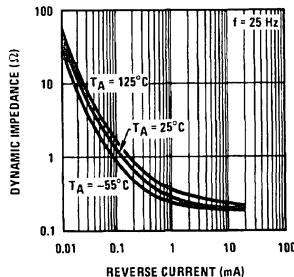
Forward Characteristics



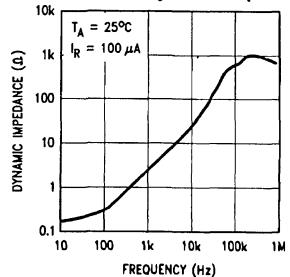
Temperature Drift of 3 Representative Units



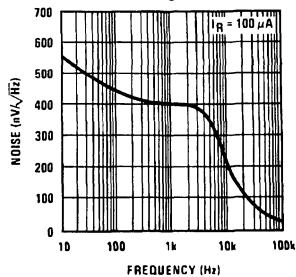
Reverse Dynamic Impedance



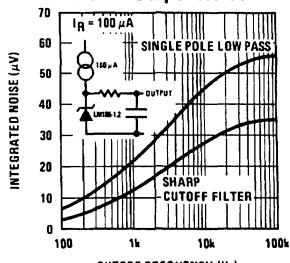
Reverse Dynamic Impedance



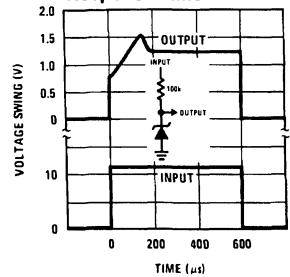
Noise Voltage



Filtered Output Noise

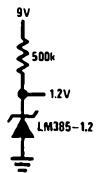


Response Time

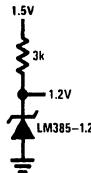


Applications (Continued)

Micropower Reference from 9V Battery



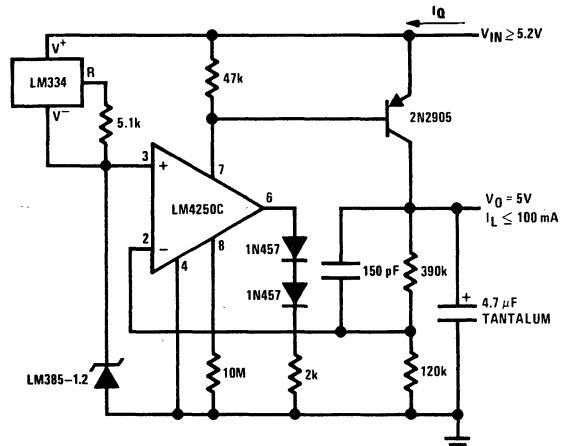
Reference from 1.5V Battery



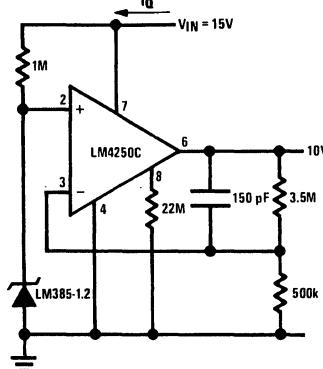
TL/H/5518-2

LM385 Applications

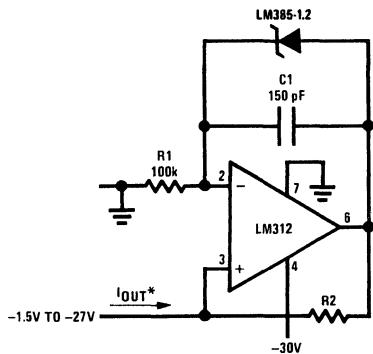
Micropower* 5V Regulator

 $*I_Q \approx 30\text{ }\mu\text{A}$

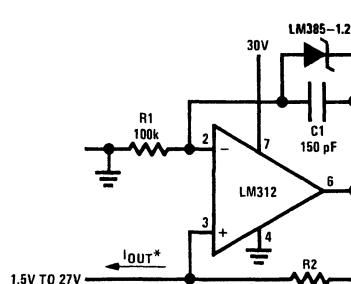
Micropower* 10V Reference

 $*I_Q \approx 20\text{ }\mu\text{A}$ standby current

Precision 1 μA to 1 mA Current Sources



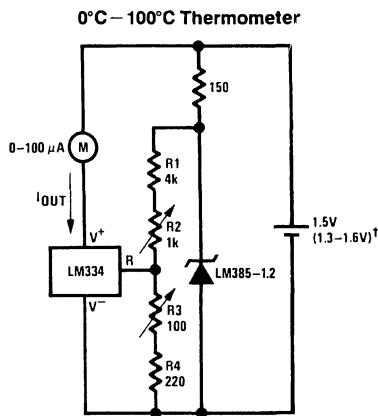
$$*I_{OUT} = \frac{1.23V}{R_2}$$



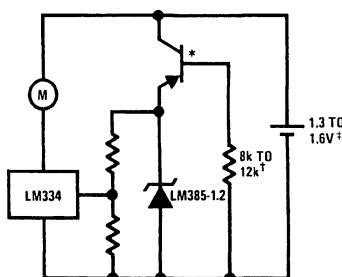
TL/H/5518-4

LM385 Applications (Continued)

METER THERMOMETERS



Lower Power Thermometer



* 2N3638 or 2N2907 select for inverse $HFE \approx 5$

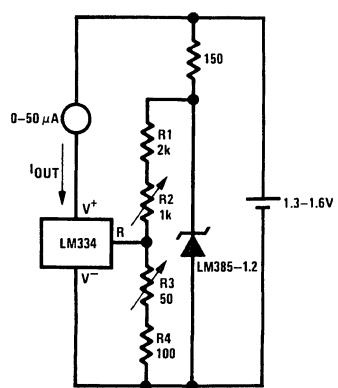
† Select for operation at 1.3V

‡ $I_Q \approx 600 \mu A$ to $900 \mu A$

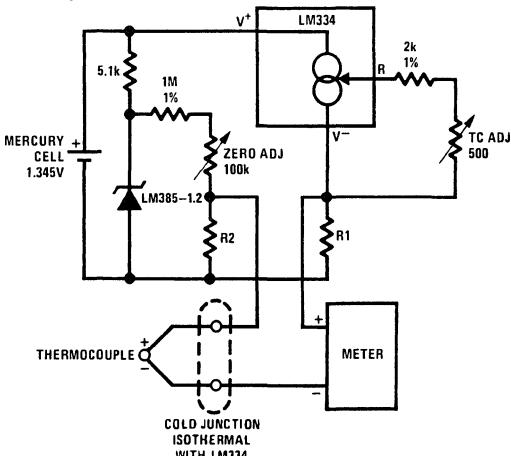
Calibration

1. Short LM385-1.2, adjust R3 for $I_{OUT} = \text{temp}$ at $1 \mu A/K$
2. Remove short, adjust R2 for correct reading in centigrade
 I_Q at 1.3V $\approx 500 \mu A$
 I_Q at 1.6V $\approx 2.4 \text{ mA}$

0°F – 50°F Thermometer



Micropower Thermocouple Cold Junction Compensator



TL/H/5518-5

Calibration

1. Short LM385-1.2, adjust R3 for $I_{OUT} = \text{temp}$ at $1.8 \mu A/K$
2. Remove short, adjust R2 for correct reading in °F

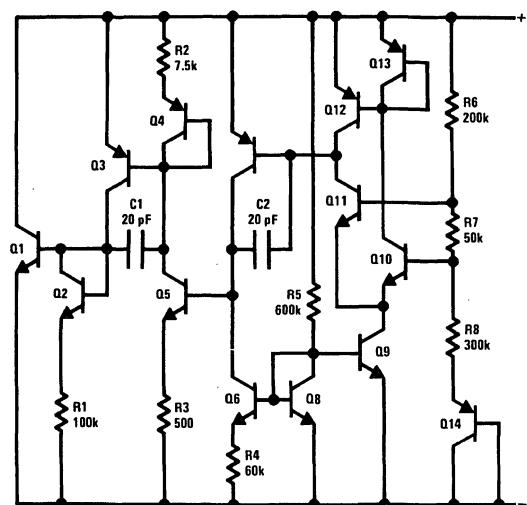
Adjustment Procedure

1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.
2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

Thermocouple Type	Seebeck Coefficient ($\mu V/^{\circ}C$)	R1 (Ω)	R2 (Ω)	Voltage Across R1 @ 25°C	Voltage Across R2 (mV)
J	52.3	523	1.24k	15.60	14.32
T	42.8	432	1k	12.77	11.78
K	40.8	412	953Ω	12.17	11.17
S	6.4	63.4	150Ω	1.908	1.766

Typical supply current 50 μA

Schematic Diagram



TL/H/5518-7